

2SK2221-E Information



For Reference Only

Part Number 2SK2221-E

ManufacturerRenesas Electronics AmericaCategoryDiscrete Semiconductor Products
Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 200V 8A TO-3P

Package TO-3P-3, SC-65-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









2SK2221-E Specifications

Manufacturer Part Number	2SK2221-E
Manufacturer	Renesas Electronics America
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-3P-3, SC-65-3
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	200V
Current - Continuous Drain (Id) @ 25°C	8A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	-
Vgs(th) (Max) @ Id	-
Gate Charge (Qg) (Max) @ Vgs	-
Input Capacitance (Ciss) (Max) @ Vds	600pF @ 10V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	100W (Tc)
Rds On (Max) @ Id, Vgs	-
Operating Temperature	150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-3P
Package / Case	TO-3P-3, SC-65-3
	Report errors?

2SK2221-E Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

2SK2221-E Payment Methods





















2SK2221-E Shipping Methods













If you have any question about 2SK2221-E, please do not hesitate to contact us!

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